ECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION



below med inventor, I hereby declare that my residence, post office address and citizenship are as stated below next to my name, and I the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

METHOD OF FORMING SILICON OXIDE FILM AND FORMING APPARATUS THEREOF

the specification of which (check one)			
( ) is attached hereto: $(x)$ was filed on $3/27/200$	01 25 United States Application	on Number or PCT International	Application Number 09/818,972
on, and was amended	d on (if app	olicable).	
I hereby state that I have reviewed and uncamendment referred to above. I acknowled Federal Regulation, §1.56. I hereby claim for patent or inventor's certificate listed be disclosing the subject matter claimed in the or (2) if no priority is claimed, before the form	dge the duty to disclose informa foreign priority benefits under low and have also identified bel eir application and having a fili	ation which is material to patent Title 35, United States Code, §1 low any foreign application for p	ability as defined in Title 37, Code of 19/365 of any foreign application(s) patent or inventor's certificate
	Prior foreign A	pplication(s)	
Number	Country	Day/Month/Year Filed	Priority Claimed
211005/2000	Japan	12/7/2000	(X) Yes ( ) No
			( ) Yes ( ) No
			( ) Yes ( ) No
information which is material to patentabil filing date of the prior application and the  (Application Number)  Day/M  I hereby appoint Donald W. Muirhead, Re	national or PCT international fi	ling date of this application.  Status (Patented, Pending, Aban	doned)
prosecute this application and to transact a	g. No. 33,978, Affice E. Saturne Ill business in the Patent and Tra	ademark Office connected there	with.
Address all telephone calls to Donald W. M.	Muirhead at telephone number (	617) 951-6676. Address all cor	respondence to:
	Patent Group Hutchins, Wh 101 Federal S Boston, MA		
I hereby declare that all statements made helieved to be true; and further that these spunishable by fine or imprisonment, or bo jeopardize the validity of the application of	statements were made with the leth, under Section 1001 of Title or any patent issued thereon.	cnowledge that willful false state 18 of the United States Code and	ements and the like so made are d that such willful false statements may
Inventor's signature Kats	nhisa Yuda	D:	ate June 25, 2001
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( ) Addition	remond are being named b		